



A Product Line of **Diodes Incorporated** 

#### LITE-ON SEMICONDUCTOR

# **MBR20150CTW**

# SCHOTTKY BARRIER RECTIFIERS

#### **FEATURES**

- · Metal of silicon rectifier, majority carrier conduction
- · Guard ring for transient protection
- Low power loss, high efficiency
- High surge & current capability, low V<sub>F</sub>
- Qualification is according to AEC-Q101 Rev C
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **APPLICATION**

· For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

#### **MECHANICAL DATA**

- Package: JEDEC TO-220AB
- Package Material: "Geen" molding compound UL flammability classification 94V-0, "Halogen-free"
- Marking Code: MBR20150CTW
- · Polarity: As marked on the body
- Weight: 1.927 grams
- Mounting Position: Any
- Max. mounting torque = 0.5N.m (5.1Kgf-cm)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

| PARAMETER  |   |  | SYMBOL           | VALUE                        | UNIT     |
|--|---|--|------------------|------------------------------|----------|
| Maximum Repetitive Peak Reverse Voltage @IR=100uA                                    |   | Vrrm                                       | 150              | V                            |          |
| Maximum DC Blocking Voltage @I <sub>R</sub> =100uA                                   |   | V <sub>DC</sub>                            | 150              | V                            |          |
| Average Rectified Output Current @T <sub>C</sub> =140°                               |   | @T <sub>C</sub> =140°C                     | lF               | 20                           | А        |
| Peak Forward Surge Current 8.3ms Single Half Sine-Wave<br>Superimposed on Rated Load |   |  | IFSM             | 180                          | А        |
| Maximum Forward Voltage<br>(Note 4)  | • | TJ=25°C<br>TJ=125°C<br>TJ=25°C<br>TJ=125°C | VF               | 0.92<br>0.75<br>1.00<br>0.86 | v        |
| Maximum DC Reverse Current at Rated DC Tj=25°C<br>Blocking Voltage Tj=125°C          |   |  | I <sub>R</sub>   | 8<br>5                       | uA<br>mA |
| Typical Junction Capacitance per Element (Note 5)                                    |   |  | Cj               | 170                          | pF       |
| Typical Thermal Resistance Junction to Case (Note 6)                                 |   |  | Rejc             | 2                            | °C/W     |
| Typical Thermal Resistance Junction to Lead (Note 6)                                 |   |  | R⊖jL             | 3                            | °C/W     |
| Typical Thermal Resistance Junction to Ambient (Note 6)                              |   |  | R⊖Ja             | 4                            | °C/W     |
| Operating Junction Temperature Range   |   |  | TJ               | -55 to +175                  | °C       |
| Storage Temperature Range  |   |  | T <sub>STG</sub> | -55 to +175                  | °C       |

#### Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. 300us Pulse Width, 2% Duty Cycle.
- 5. Measured at 1.0MHz and applied reverse voltage of 4.0  $V_{\text{DC}}.$
- 6. Thermal Resistance Junction to Case. The unit mounted on fin-type heatsink 42 x 25 x 25mm.

#### **REVERSE VOLTAGE** - 150 Volts FORWARD CURRENT

- 20 Amperes

TO-220AB

MIN.

14.40

9.65

2.54

5.84

8.26

-

12.70

2.29

0.51

0.30

3.56

1.14

2.03

1.14

3.53 ø

MAX.

15.20

10.67

3.43

6.86

9.28

4.20

14.73

2.79

1.14

0.64

4.83

1.40

2.92

1.70

4.09 ø

DIM.

A

В

С

D

Е

F

G

Н

Т

J

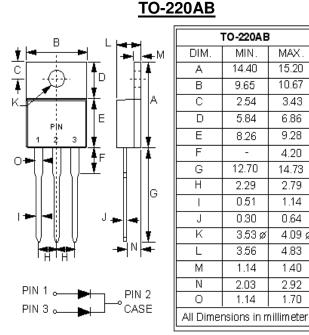
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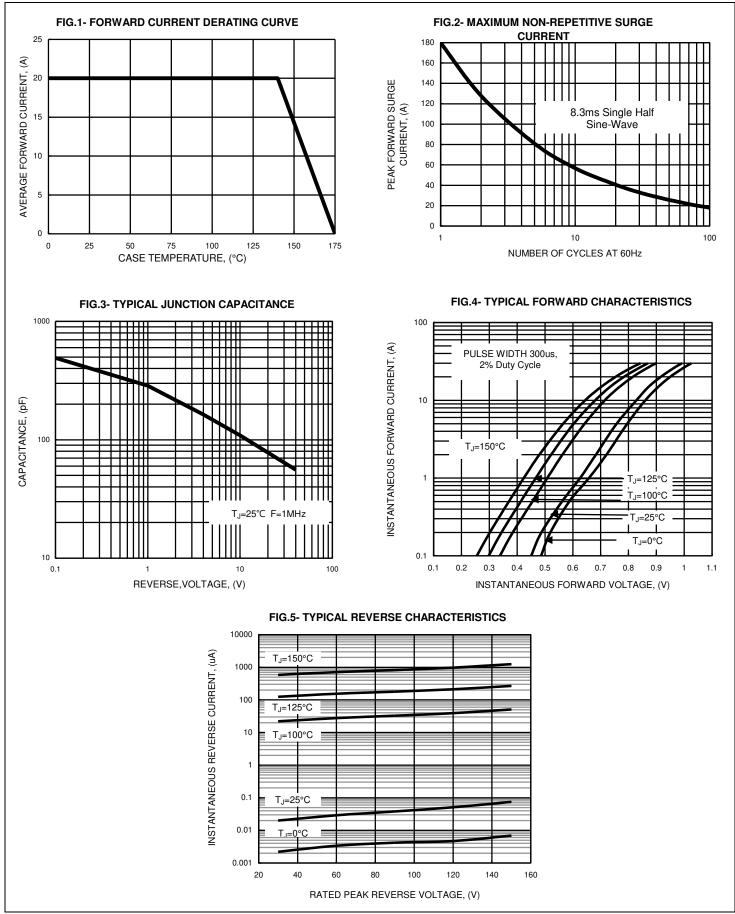
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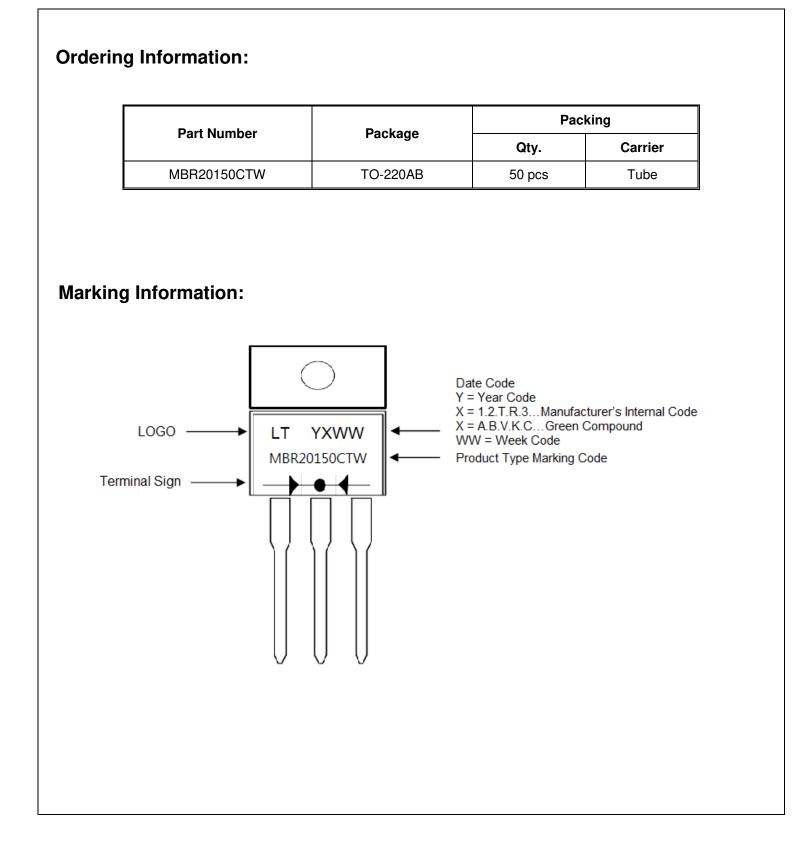


# RATING AND CHARACTERISTIC CURVES MBR20150CTW

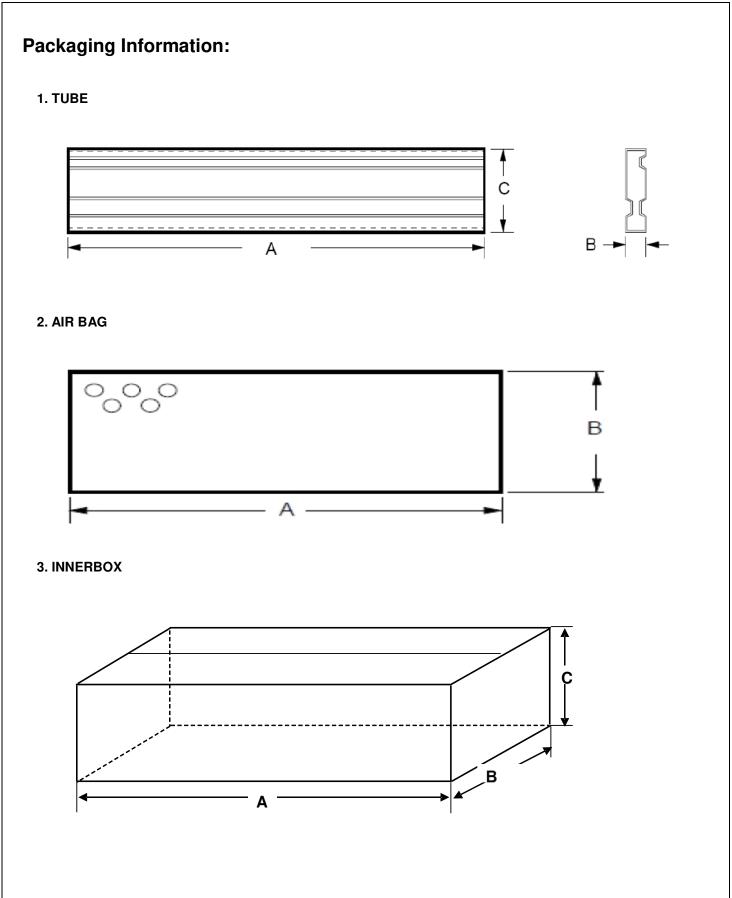
## LITE-ON SEMICONDUCTOR







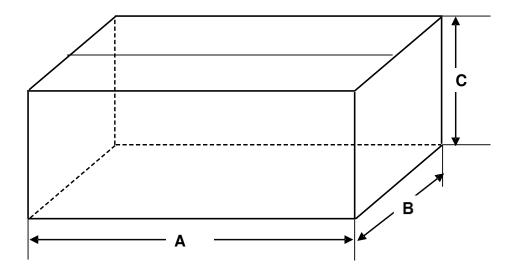






# **Packaging Information:**

## 4. CARTON



#### Unit:mm

| P/N      | DIMENSION<br>"A" | DIMENSION<br>"B" | DIMENSION<br>"C" | Q'ty/per | REMARK         |
|----------|------------------|------------------|------------------|----------|----------------|
| TUBE     | 536              | 5.6              | 31.8             | 50       | /              |
| AIR BAG  | 800              | 550              | /                | /        | /              |
| INNERBOX | 555              | 165              | 105              | 2000     | 40TUBE         |
| CARTON   | 575              | 179              | 225              | 4K       | 2 INNER<br>BOX |



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